

Provisional Data

Wespack Phase Control Thyristor Types N3597ML020 to N3597ML060

Development Type No.: NX313ML020-060

Absolute Maximum Ratings

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
V_{DRM}	Repetitive peak off-state voltage, (note 1)	200-600	V
V_{DSM}	Non-repetitive peak off-state voltage, (note 1)	200-600	V
V_{RRM}	Repetitive peak reverse voltage, (note 1)	200-600	V
V_{RSM}	Non-repetitive peak reverse voltage, (note 1)	300-700	V

	OTHER RATINGS	MAXIMUM LIMITS	UNITS
$I_{T(AV)M}$	Maximum average on-state current, $T_{sink}=55^{\circ}C$, (note 2)	3597	A
$I_{T(AV)M}$	Maximum average on-state current. $T_{sink}=85^{\circ}C$, (note 2)	2588	A
$I_{T(AV)M}$	Maximum average on-state current. $T_{sink}=85^{\circ}C$, (note 3)	1244	A
$I_{T(RMS)M}$	Nominal RMS on-state current, $T_{sink}=25^{\circ}C$, (note 2)	7030	A
$I_{T(d.c.)}$	D.C. on-state current, $T_{sink}=25^{\circ}C$, (note 4)	5616	A
I_{TSM}	Peak non-repetitive surge $t_p=10ms$, $V_{rm}=60\%V_{RRM}$, (note 5)	45.4	kA
I_{TSM2}	Peak non-repetitive surge $t_p=10ms$, $V_{rm}\leq 10V$, (note 5)	50.0	kA
I^2t	I^2t capacity for fusing $t_p=10ms$, $V_{rm}=60\%V_{RRM}$, (note 5)	10.3×10^6	A^2s
I^2t	I^2t capacity for fusing $t_p=10ms$, $V_{rm}\leq 10V$, (note 5)	12.5×10^6	A^2s
$(di/dt)_{cr}$	Critical rate of rise of on-state current (note 6)	(continuous, 50Hz)	100
		(repetitive, 50Hz, 60s)	200
		(non-repetitive)	400
V_{RGM}	Peak reverse gate voltage	5	V
$P_{G(AV)}$	Mean forward gate power	4	W
P_{GM}	Peak forward gate power	30	W
$T_{j\ op}$	Operating temperature range	-40 to +140	$^{\circ}C$
T_{stg}	Storage temperature range	-40 to +150	$^{\circ}C$

Notes:-

- 1) De-rating factor of 0.13% per $^{\circ}C$ is applicable for T_j below $25^{\circ}C$.
- 2) Double side cooled, single phase; 50Hz, 180° half-sinewave.
- 3) Cathode side cooled, single phase; 50Hz, 180° half-sinewave.
- 4) Double side cooled.
- 5) Half-sinewave, $140^{\circ}C$ T_j initial.
- 6) $V_D=67\% V_{DRM}$, $I_{TM}=2000A$, $I_{FG}=2A$, $t_r\leq 0.5\mu s$, $T_{case}=140^{\circ}C$.

Characteristics

	PARAMETER	MIN.	TYP.	MAX.	TEST CONDITIONS (Note 1)	UNITS
V _{TM}	Maximum peak on-state voltage	-	-	1.05	I _{TM} =4000A	V
V _{TM}	Maximum peak on-state voltage	-	-	1.53	I _{TM} =13000A	V
V _{T0}	Threshold voltage	-	-	0.840		V
r _T	Slope resistance	-	-	0.053		mΩ
(dv/dt) _{cr}	Critical rate of rise of off-state voltage	1000	-	-	V _D =80% V _{DRM} , linear ramp, gate o/c	V/μs
I _{DRM}	Peak off-state current	-	-	100	Rated V _{DRM}	mA
I _{RRM}	Peak reverse current	-	-	100	Rated V _{RDM}	mA
V _{GT}	Gate trigger voltage	-	-	3.0	T _j =25°C V _D =10V, I _T =3A	V
I _{GT}	Gate trigger current	-	-	300		mA
V _{GD}	Gate non-trigger voltage	-	-	0.25	Rated V _{DRM}	V
I _H	Holding current	-	-	1000	T _j =25°C	mA
t _{gd}	Gate-controlled turn-on delay time	-	0.7	2.0	V _D =67% V _{DRM} , I _T =2000A, di/dt=10A/μs,	μs
t _{gt}	Turn-on time	-	1.3	3.0	I _{FG} =2A, t _r =0.5μs, T _j =25°C	μs
Q _{rr}	Recovered charge	-	1300	-		μC
Q _{ra}	Recovered charge, 50% Chord	-	750	850	I _{TM} =1000A, t _p =1000μs, di/dt=10A/μs,	μC
I _{rr}	Reverse recovery current	-	95	-	V _r =50V	A
t _{rr}	Reverse recovery time	-	16	-		μs
t _q	Turn-off time	-	200	-	I _{TM} =1000A, t _p =1000μs, di/dt=10A/μs,	μs
		-	260	-	V _r =50V, V _{dr} =80%V _{DRM} , dV _{dr} /dt=20V/μs	
R _{thJK}	Thermal resistance, junction to heatsink	-	-	0.018	Double side cooled	K/W
		-	-	0.033	Anode side cooled	K/W
		-	-	0.044	Cathode side cooled	K/W
F	Mounting force	25	-	31	Note 2.	kN
W _t	Weight	-	550	-		g

Notes:-

- 1) Unless otherwise indicated T_j=140°C.
- 2) For other clamp forces, please consult factory.

Curves

Figure 1 – On-state characteristics of Limit device

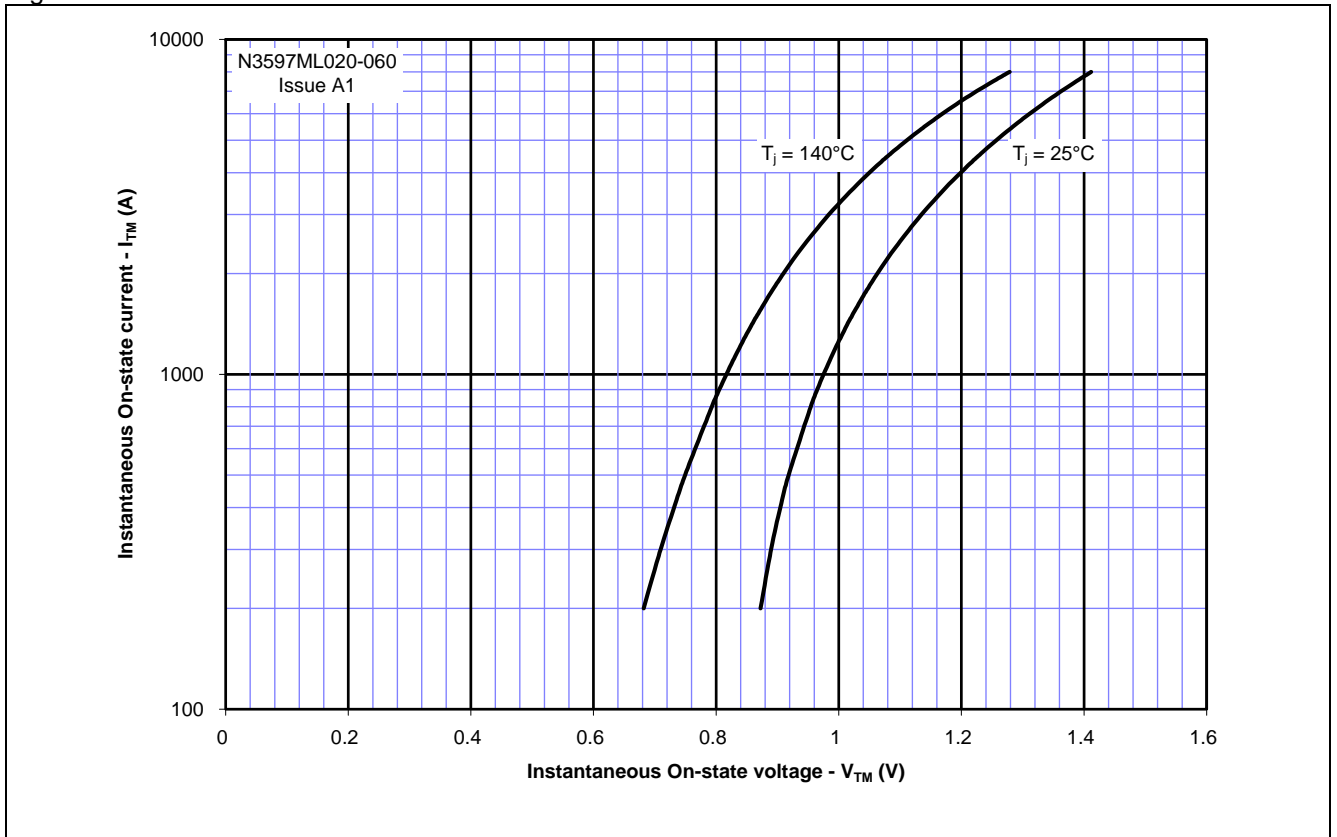


Figure 2 – Transient thermal impedance

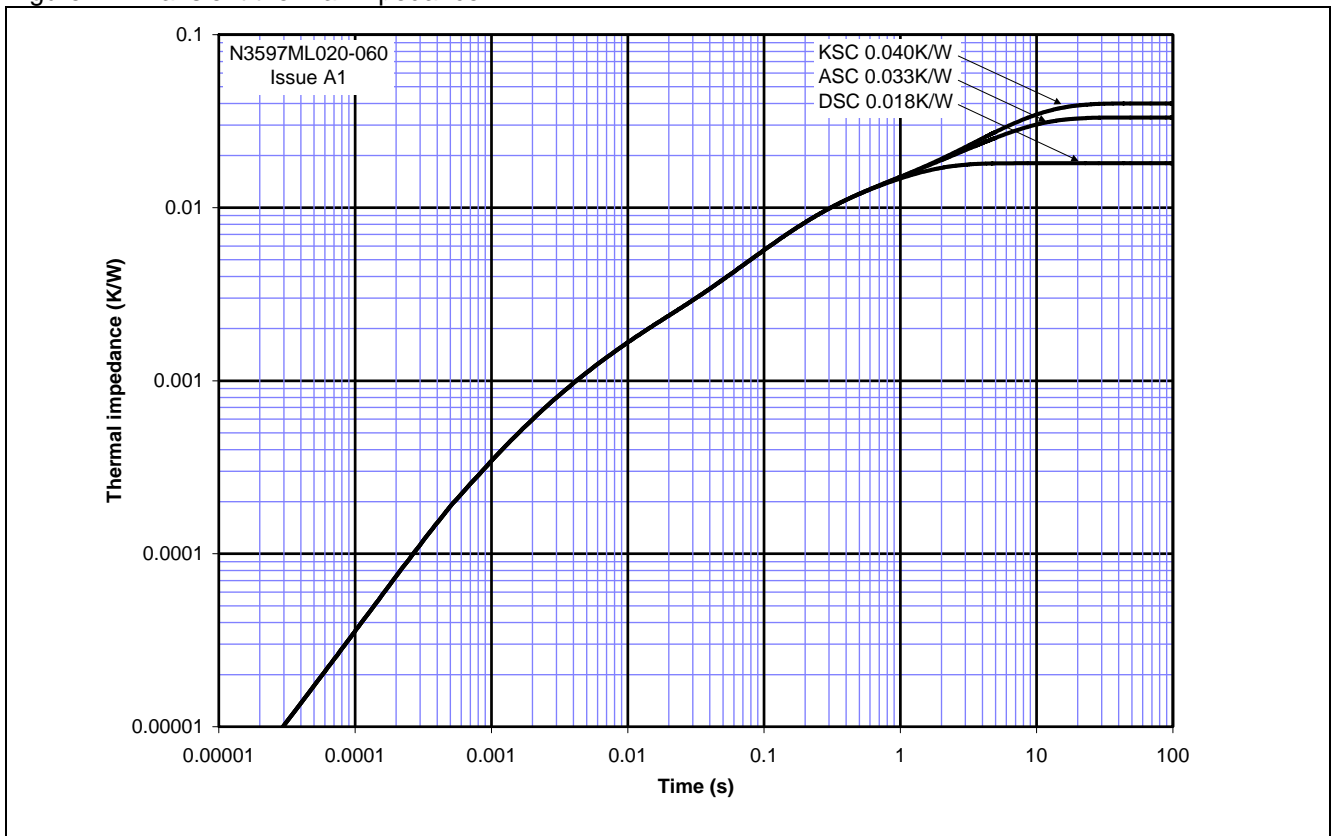
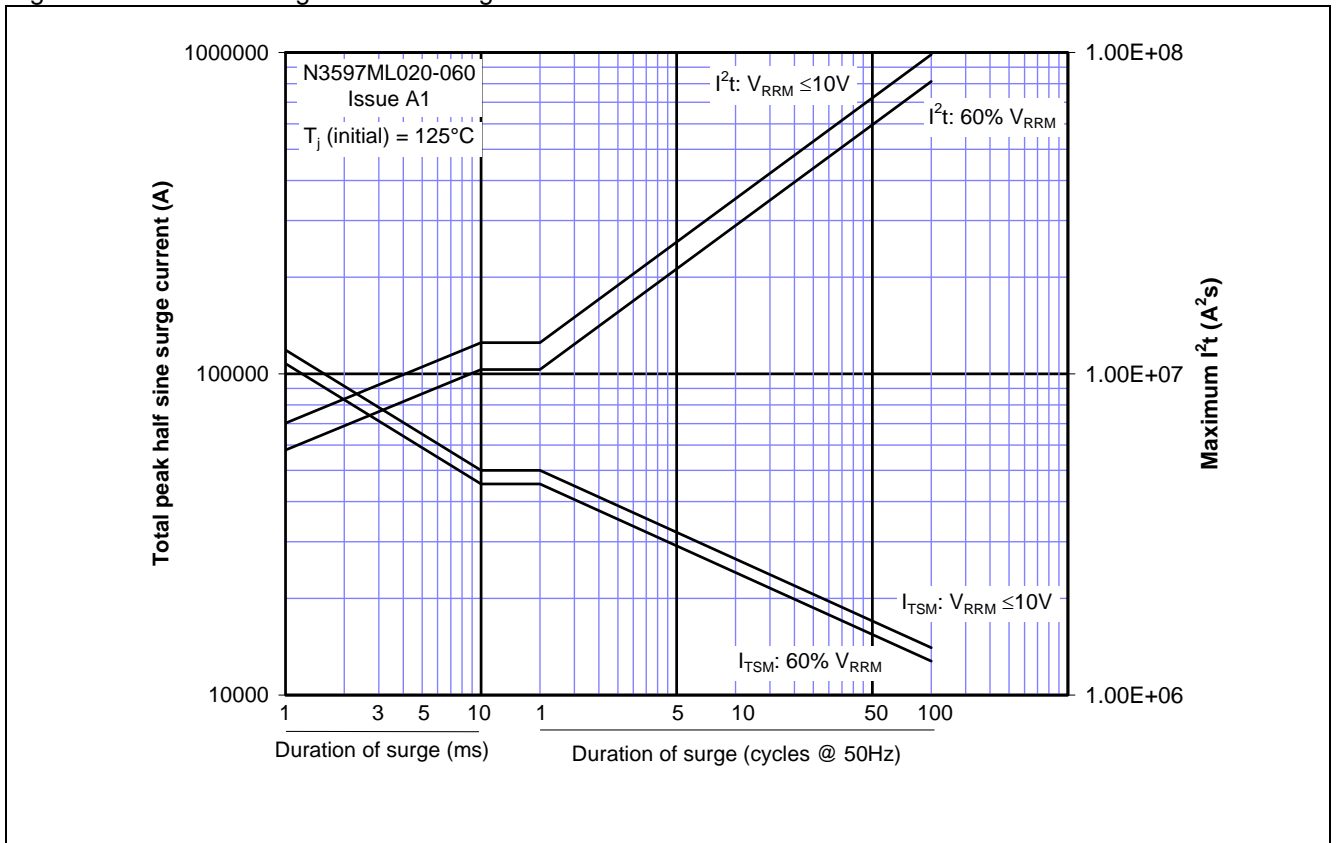
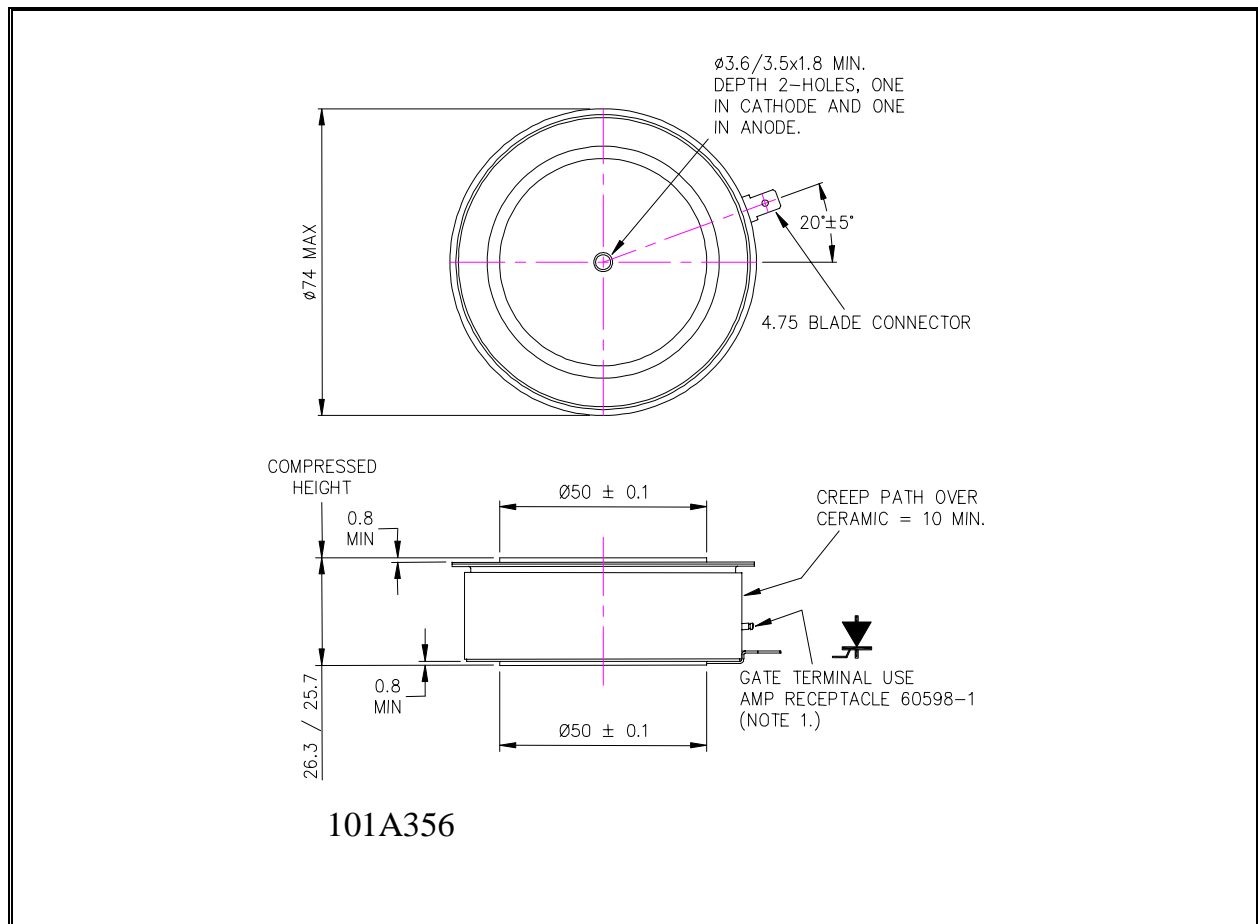


Figure 3 – Maximum surge and I^2t Ratings



Outline Drawing & Ordering Information



ORDERING INFORMATION		(Please quote 10 digit code as below)	
N3597	ML	◆◆	0
Fixed Type Code	Fixed outline code	Voltage code $V_{DRM}/100$ 16-18	Fixed turn-off time code

Order code: N3597ML060 – 600V V_{DRM} , V_{RRM} , 26mm clamp height capsule.

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